



Low Voltage Modulators Based on Semiconductor Microresonators

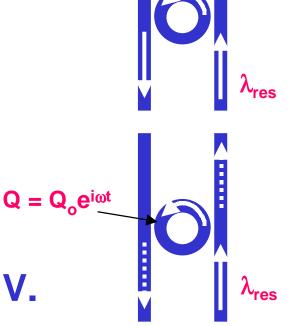
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Program Concept



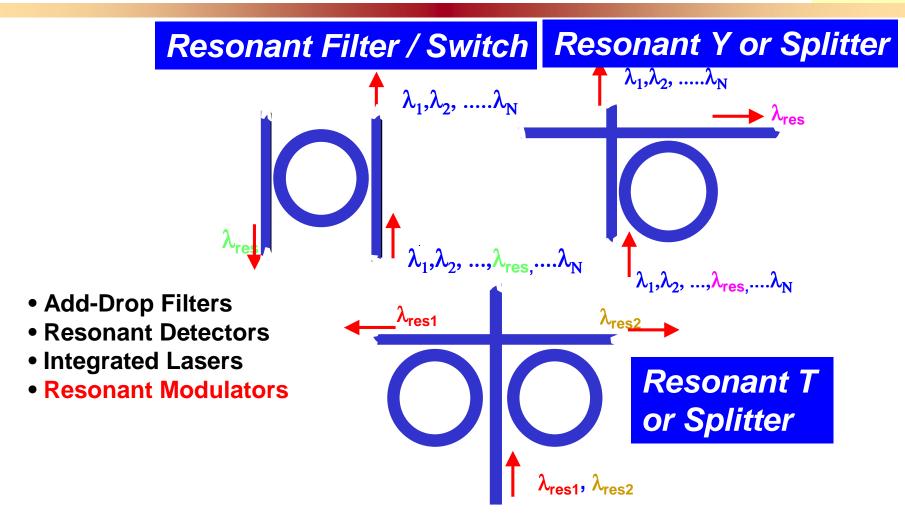
- High Q resonators enhance the coupling between waveguides.
- Low voltage modulation of the resonator Q can modulate the power transfer.
- Develop techniques for q = fabricating resonators and modulator circuits with V_p ~ 0.1 V.





μ Resonator Structures





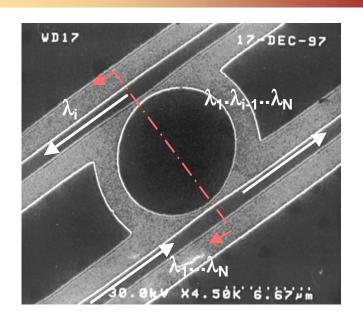
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Laterally Coupled Resonator





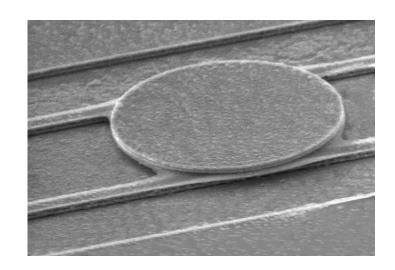
- Air coupling and guiding
- Submicron control of coupling
- Submicron waveguide widths
- Control of waveguide and resonator wall smoothness

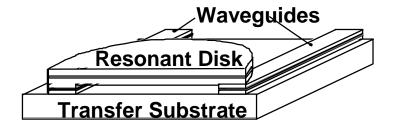




Vertically Coupled Resonator





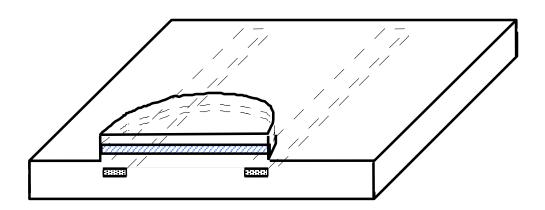


- •Epilayer coupling.
- •Control coupling by epilayer thickness.
- •Flexible single mode waveguide design.
- Integration of active and passive structures.
- Separates resonator and coupler fabrication



Integration Challenges





Uniform resonator potential / current flow

Buried or ridge waveguides?

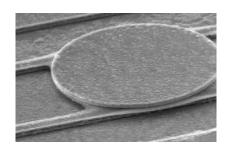
Rings or disk resonator?

Regrowth or wafer bonding?



Loss and Q Control





Residual absorption in resonator

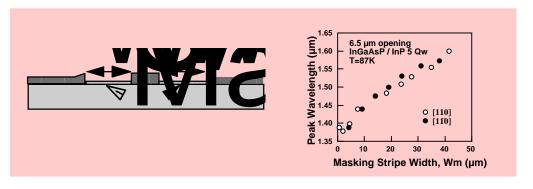
Scattering at edges

Controlled coupling

Insertion loss

Mode matching

Tapered Mode Couplers



(a) 0.5 μm

(a) 0.5 μm

(b) 0.5 μm

(c) 1 1 to junc.

(d) 1 to junc.

(e) 1 to junc.

(e) 1 to junc.

(f) 2 to junc.

(f) 3 to junc.

(f) 4 t

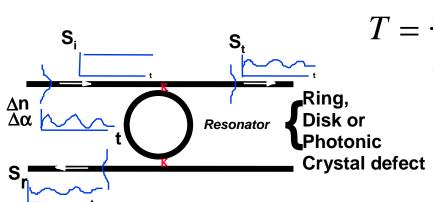
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Resonator Response





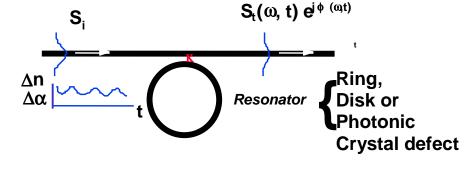
$$T = \frac{j(\omega - \omega_0)/\omega_o + (Q_l^{-1} - Q_c^{-1})/2}{j(\omega - \omega_0)/\omega_o + (Q_l^{-1} + Q_c^{-1})/2}$$

At resonance:

T is 0 when $Q_I = Q_c$

T exhibits a π phase change

T is a minimum unless $Q_1 >> Q_c$ then T = 1



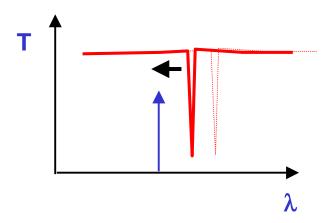
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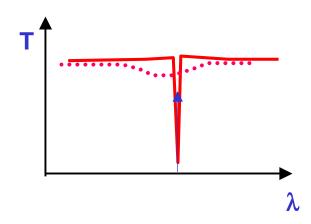
Modulation Mechanisms





Resonance Tuning

Electro optic Effect Electroreflectance Effect Free Carrier



Q Tuning

Electroabsorption
Gain
Electroreflectance

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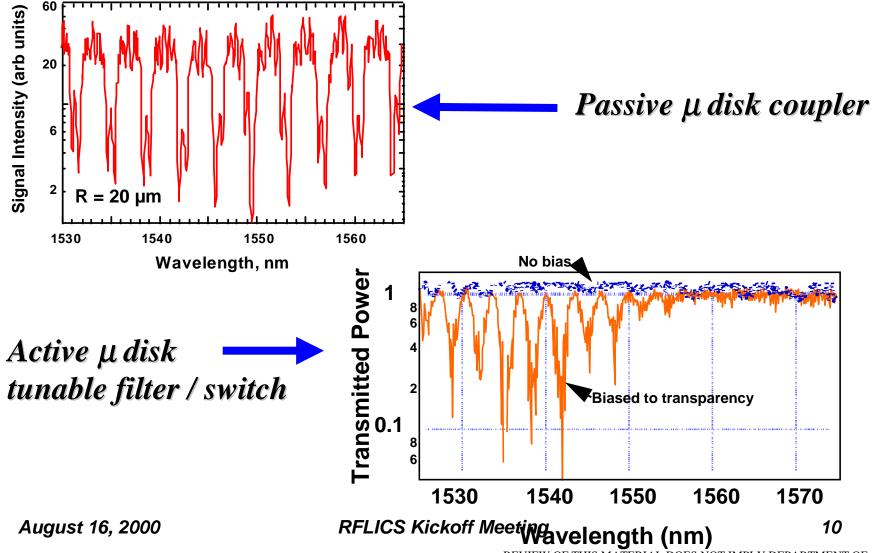
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Q



μ Disk Resonant Components

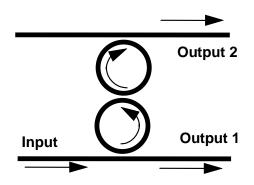




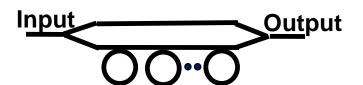


Resonator Circuits





- Shaped Resonance Response
- Venier Resonance Control



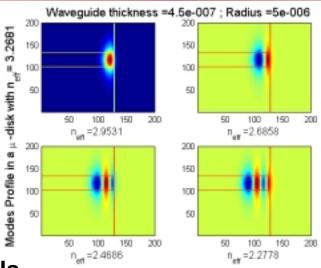
- Traveling Wave Drive
- Additive Phase Changes
- Push Pull Drive



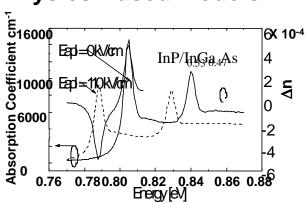
Modeling Tools



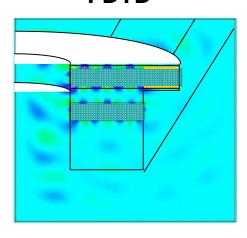
Finite Difference Mode Solvers



Physics Based Models



FDTD



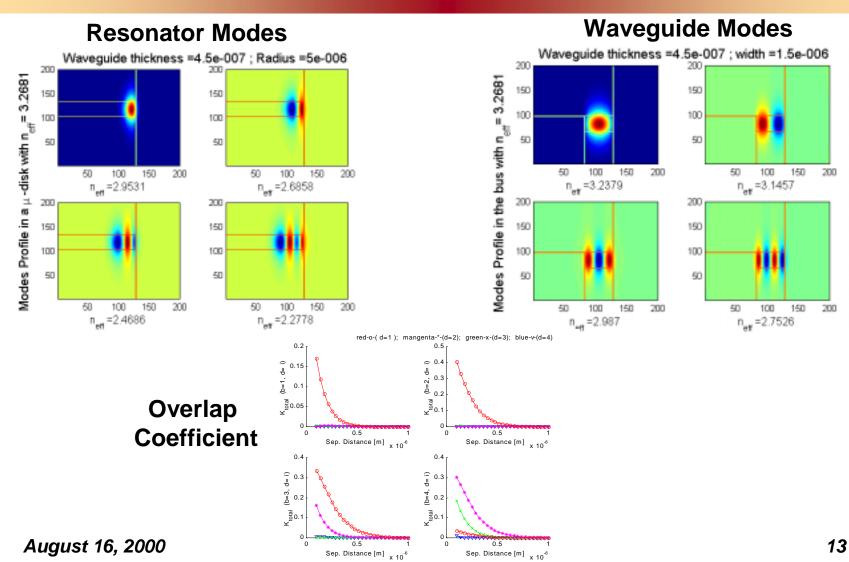
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Waveguide / resonator coupling

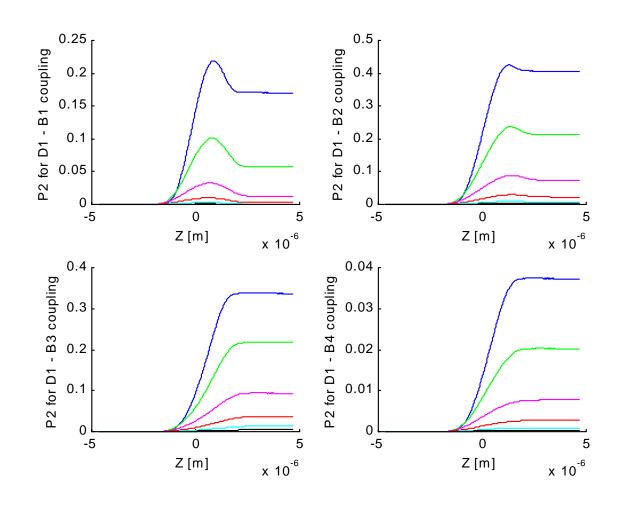






Coupling Coefficeint





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Technology Output



- 1. Low Voltage Modulators with low insertion loss
- 2. Vertically coupled WDM component technology.
- 3. Suite of sophisticated modeling tools.
- 4. Deliverable modulators for system trials.



Tasks and Milestones



- Task 1 Modeling of Modulator Design and Characteristics
 - Preliminary designs of EA and ER modulators. 3Q
 - Theoretically optimized coupling design. 8Q
- Task 2 Modulator Fabrication Technology Advancement
 - Resonator fabrication approach chosen. 4Q
 - Fabrication process optimized. 8Q
 - Vertical Integration approach choice. 10Q
- Task 3 Modulator Optimization
 - Residual loss near E_G characterized vs λ. 3Q
 - EA vs. ER choice made. 8Q
 - Ring vs Disk scattering loss measurement. 4Q
 - Measurement of Q-limited modulation limit. 10Q
 - Low resistance contact demonstrated. 4Q
 - Air bridge technology demonstration. 10Q
- Task 4 Modulator Demonstration, Characterization and Delivery
 - DC characterization setup complete. 4Q
 - High frequency modulation characterization setup complete. 6Q
 - Eight (8) low V_{π} modulators delivered in years 1-3 according to selected integrator. 12Q